

SOME CONSIDERATION ON DOUBLE LAYER STRUCTURE IN PLASMA ASSISTED NITRIDING OF AUSTENITIC STAINLESS STEEL

N. Parvini Ahmadi & T. Czerwiec

Abstract: Low temperature plasma assisted nitriding treatments of 316 stainless steel produce a complex layer constituted by two different metastable f.c.c. solid solution denoted (γ_{N1} and γ_{N2}). About the formation of these double layers, different hypothesis was proposed in the literature. For verifying these hypotheses, the effects of different conditions such as nitriding temperature, cleaning and nitriding duration and cooling state have been studied. The results show that γ_{N2} sub layer produce during the ion bombardment cleaning procedure, before the nitriding treatment. Also the formation of the γ_{N2} layer is not connected to the cooling state of the sample after nitriding treatment.

Keywords: Plasma Assisted, Nitriding, Stainless Steel, Double Layer

1. Introduction

Stainless steel plays an important role in various sectors of industry owing to their excellent corrosion resistance. But their application is limited by their relative low hardness. During the past two decades, much work has been carried out on the nitriding of stainless steel, so as to improve their hardness and wear resistance [1-10]. Low temperature plasma based nitriding has been proved to be an efficient way to form a very hard and corrosion-resistant layer on the surface of austenitic steels with relative high chromium content [2, 6, 8]. Such a layer is called expanded austenite [11], γ_N phase [12, 13], s phase [14] or m phase [15]. In this paper, it is called γ_N phase. The possible occurrence of double layer constituted by two different metastable f.c.c. solid solutions denoted (γ_{N1} and γ_{N2}) was reported for AISI 316 austenitic stainless steel [10, 16]. Williamson et al. [10] observed a double layer structure corresponding to two well-defined N contents: 20-26 at% in the γ_{N1} surface layer and 4-10 at% in the γ_{N2} subsurface layer when nitriding Fe-rich f.c.c. alloys. They have suggested that γ_{N2} formation is caused by stress-assisted diffusion. The other searchers speculated that this double layer structure is formed during the slow cooling of the substrate after nitriding. The aim of this paper is to study this double layer structure in order to verify the different hypothesis proposed in the literature.

2. Experimental Details

2-1. Sample Preparation

Two types of AISI 316L (13%Ni, 17%Cr, 67%Fe, 2%Mo, 0.5%Si, 0.2%Mn, 0.02%C, other balance) and AISI304 (9.5%Ni, 18%Cr, 69.43%Fe, 1%Si, 2%Mn, 0.07%C, other balance) stainless steel samples were used in this study. The samples were cut from a cylindrical bar which has been annealed at 900°C for 24 hours, subsequently machined to a 20 mm in diameter, 4mm in thickness disk, then grounded and mechanically polished to a mirror-like finish. The samples were always polished by 1 μ m diamond paste and then cleaned in methanol for 15 minutes by using ultrasonic just before being placed into the reactor chamber

2-2. Nitriding Process

Plasma nitriding is realized using an 800 Hz pulsed Dc discharge, with a 0.8 duty cycle ratio (ratio of the pulse duration to the pulse period) in a DC pulse plasma reactor. Normally, the sample is screwed into the substrate holder so that they form a continuous surface in order to avoid edge effects. However, the substrates are placed on a flat substrate holder in some experiments in order to allow oil quenching at the end of the treatment by simply pushing the sample in a oil container. An in situ cleaning procedure, intended to remove the native oxide layer and to simultaneously heat the sample to the working temperature, is performed before the nitriding treatment in a 50%Ar-50%H₂ plasma under a 200 Pa pressure. The nitriding treatment is then performed in a 90%N₂ - 10%H₂ gas mixture. The temperature is measured by a thermocouple embedded into the substrate holder. At the end of a normal treatment, the samples are allowed

Paper first received Feb. 10, 2003 and in revised form April, 05, 2005.

N. Parvini Ahmadi, Department of Materials Engineering, Sahand University of Technology, Tabriz, Iran, parvini@sut.ac.ir

T. Czerwiec, Laboratoire de Science et Genie de Surfaces (UMR CNRS 7570), Ecole des Mines, Parc de Saurupt, 54042 Nancy Cedex, France.; parvini@sut.ac.ir

to cool in vacuum. Several samples are nitrided skipping the ion bombardment cleaning procedure, or merely ion bombarded in Ar-H₂ plasma, in order to reveal the effect of the in-situ cleaning treatment on the structure of the nitrided layer.

The effect of carbon contamination is investigated by introducing 0.25% CH₄ into the Ar-H₂ gas mixture during the ion bombardment cleaning procedure. Table 1 lists the processing conditions for various nitriding treatments.

3. Results and Discussion

3-1. Structure of the Nit Rided Layer

In many published papers, a layer of metastable f.c.c. solid solution supersaturated in nitrogen, also known as

expanded austenite, γ_N phase, s phase or m phase, has been reported in austenitic stainless steels which are nitrided at temperatures between 310°C and 420°C [6, 8, 11]. Fig.1shows the SEM morphology of the layer nitrided at 420°C in a 90%N₂- 10%H₂ gas mixture, (sample no. 1 in table 1). It is evident that nitrided layer is composed of dual layers with well-defined interface.

Fig. 2(b) is the correspondent XRD pattern of this sample. A characteristic set of broad diffraction lines corresponding to the γ_N phase (denoted by γ_{N1}) can be seen in the figure. At low angles, between the diffraction lines of the γ_N phase and the matrix, another peak (denoted by γ_{N2}) can be observed on the diffraction pattern.

Tab. 1. Description of the processing conditions for plasma assisted nit riding of stainless steel samples

Sample's ID	Substrate diameter(mm)	Nitriding temperature (°C)	Duration (Min)		Cooling state
			In-situ cleaning	Nitriding	
No 1 (AISI316L)	20	420	60	60	Normal
No 2 (AISI316L)	20	440	60	60	Normal
No 3 (AISI304)	20	420	60	60	Normal
No 4 (AISI304)					Quenched in oil
No 5 ^(a) (AISI316L)	20	420	60	60	Normal
No 6 (AISI316L)	20	420	-	120	Normal
No 7 (AISI316L)					Quenched in oil
No 8 (AISI316L)	20	300-440	240	-	Normal

(a) The gas mixture for ion-cleaning is different in this experiment: 50%Ar + 49.75%H₂ + 0.25%CH₄

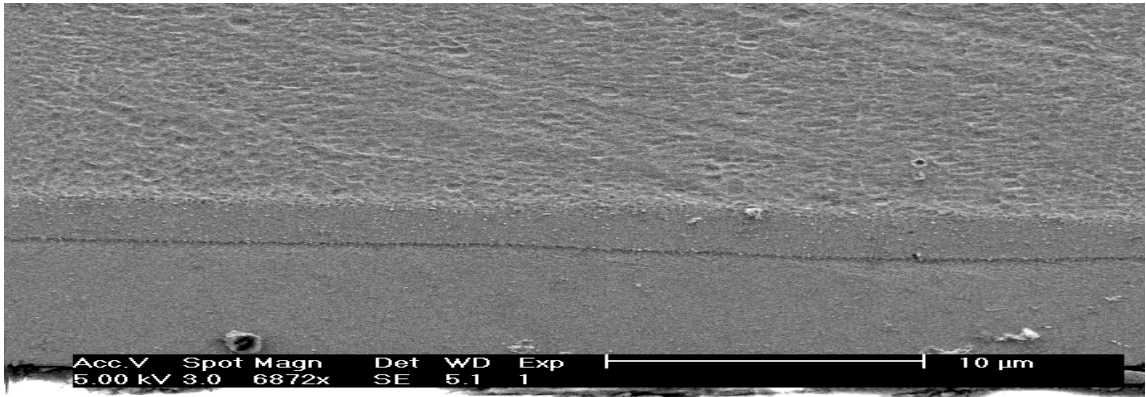


Fig. 1. SEM micrographs of the nit rided layers for sample no.1

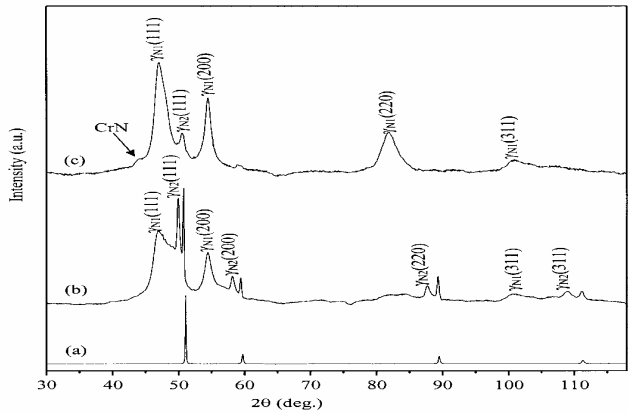


Fig. 2. XRD diffraction patterns for nit rided samples no. 1(b), no. 2(c) described in table 1, and for the AISI 316L substrate (a), with Co K α radiation at the incident angle of 10° (a, b) and 4° (c).

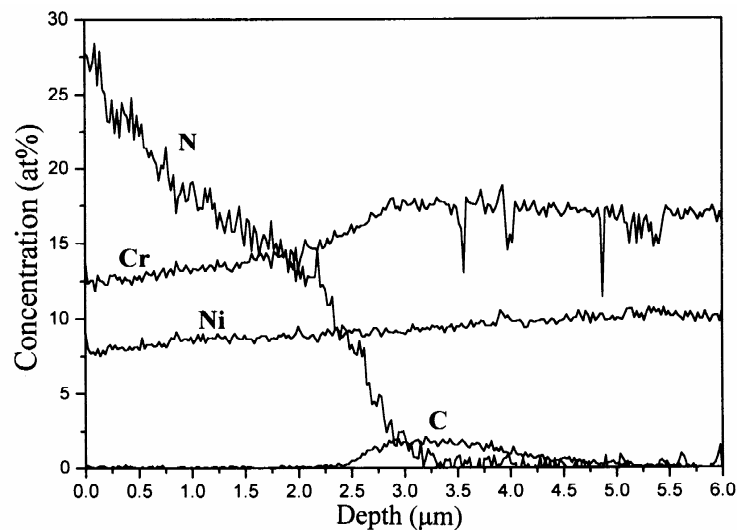


Fig. 3. SNMS concentration depth profiles of sample no.1 in table 1

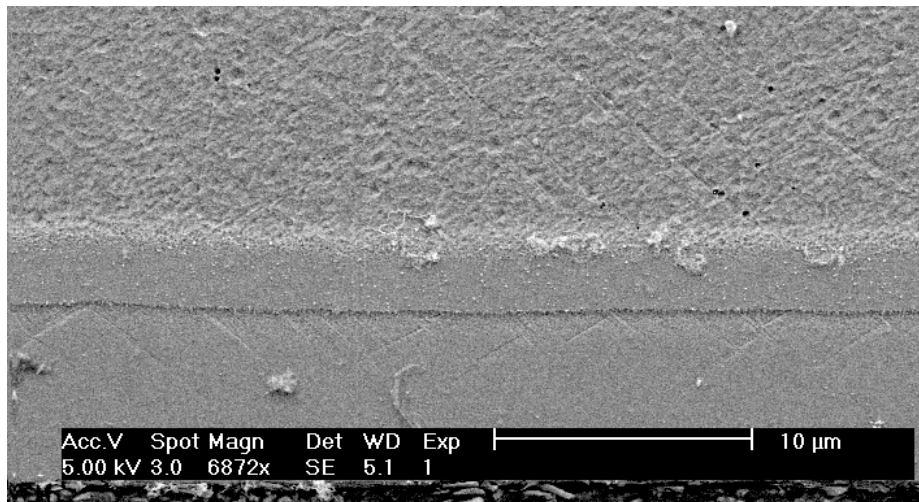


Fig. 4. SEM micrographs of the nitrided layers for sample no.2

Fig. 3 shows the concentration depth profiles obtained by SNMS (sputtered neutral mass spectrometry) of this sample. The profile of Fe element was eliminated for the sake of convenience. It can be seen that the nitrogen content in the nitrided layer abruptly decreases at a depth of 2.5 μm , which is approximately the thickness of the top layer. And accumulation of carbon element was observed between the depth of 2.5 μm and 4.5 μm , where exists the second layer. Thus, the top layer is associated to γ_{N1} phase which has a solid solution nitrogen content of 10-28 at%. And the sublayer is connected to γ_{N2} phase, which has a relatively lower nitrogen content (≤ 10 at%), and a small quantity of carbon. Table 2 lists the lattice parameters of the γ_{N1} phase, γ_{N2} phase, and total layer thickness obtained under various processing parameters.

As shown in fig.4, the dual layer structure can be also observed in the nitrided layer of an AISI 316L sample which was nitrided at 440°C in the same gas mixture (corresponding to sample no.2 in table 1). But a weak peak of CrN appears on the corresponding XRD

Pattern, fig. 2(c). This is basically in accordance with other reports that 450°C is the upper limit temperature for stainless steels to be nitrided without forming CrN precipitates [17]. It is difficult to find diffraction lines of the matrix on the diffraction pattern because an incident angle of 4° was applied to this sample during the XRD measurement.

Fig. 5 and 6 are the SEM micrographs of the AISI 304 samples of the AISI 304 samples nitrided at 420°C, which is corresponding to samples no.3 and no. 4 in table 1. The nitrided layers show a similar structure to that observed in the other type of AISI 316L, in other words, a dual layer structure can also be observed in the nitrided layer. It is noted that these two samples were nitrided at the same time under the same processing parameters, except that at the end of nitriding, sample no 3 was allowed to cool with the substrate holder, while sample no. 4 was quenched in oil. Thus this experiment indicates that formation of γ_{N2} layer probably is independent on the cooling state. Fig. 7 shows the corresponding XRD patterns of these two samples. In contrast to fig. 2, the diffraction lines

associated to the γ_{Ni} phase seen to split in two distinct parts. It is tempting to attribute these diffraction peaks to the γ' Fe_4N phase, but we believe that this effect is connected to the high stress level in the γ_{Ni} phase. Fig. 8 shows the SEM micrograph of an AISI 316L sample which was nitrided at 420°C. In this experiment

0.25% CH_4 was introduced into the reactor during the ion bombardment cleaning (corresponding to the sample no. 5 in table 1). The nitrided layer also exhibits a dual layer structure. Fig. 9 shows the corresponding XRD patterns for this sample.

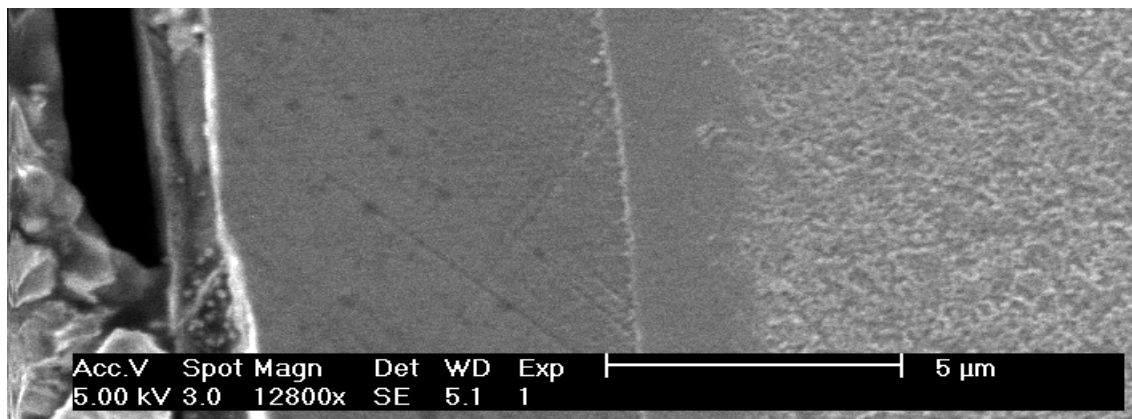


Fig. 5. SEM micrographs of the nitrided layers for sample no.3 described in table 1

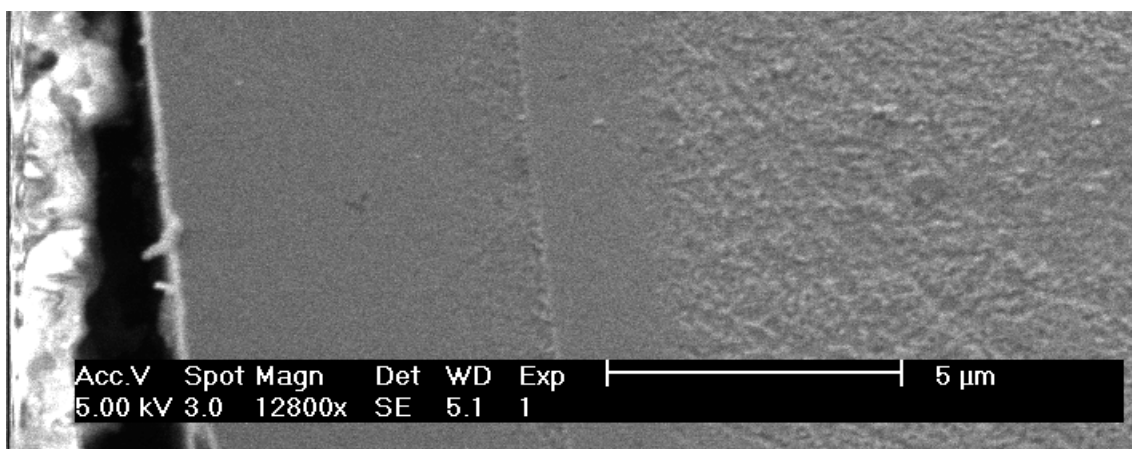


Fig. 6. SEM micrographs of the nitrided layers for sample no.4 described in table 1

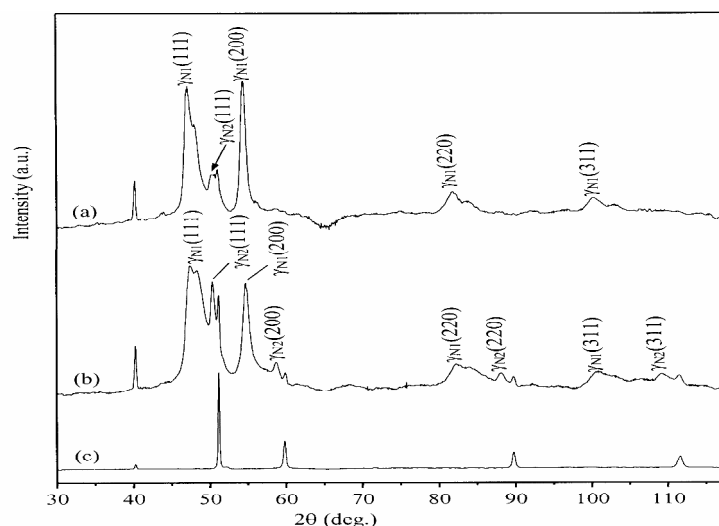


Fig. 7. XRD patterns for samples no.3(a), no.4(b) described in table 1, and for the AISI 316L substrate (c). With $\text{CoK}\alpha$ radiation at incident angle 10° .

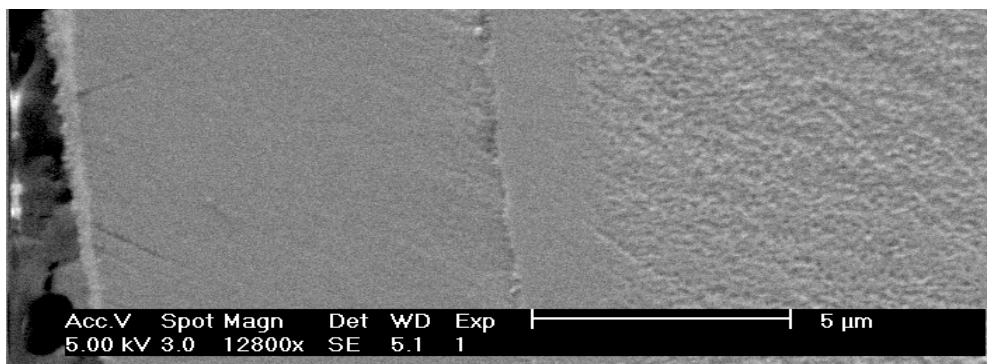


Fig. 8. SEM micrographs of the nitrided layer for sample no.5 described in table 1.

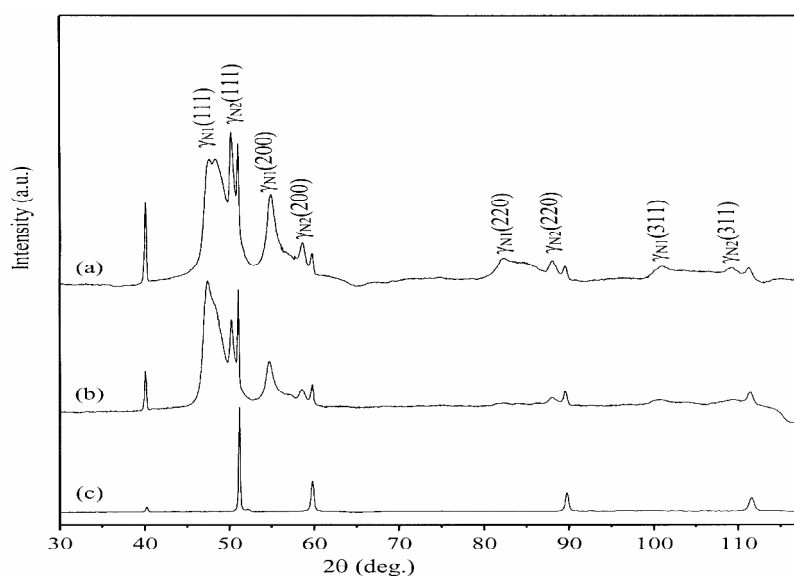


Fig. 9. XRD patterns for sample no.5 described in table 1(a) and (b), and for the original AISI 316L substrate (c), with CoK α radiation at incident angle 10° (a) and (c), and 25° (b)

Several explanations for the formation of the dual layer have been proposed. Williamson et al. [10] suggested that the formation of the γ_{N_2} phase is caused by stress-assisted diffusion. Czerwicz et al. [16] proposed that γ_{N_2} sublayer is formed during the slow cooling of the substrate after intruding. We will show a different mechanism in this paper.

4. Mechanism for the Formation of the Dual Layer Structure

Since the formation of the γ_{N_2} layer is not necessary associated with the cooling state after a nitriding treatment, it probably occurs during the nitriding or even begins during the ion bombardment cleaning procedure. Then another two experiments were carried out, referred to as samples no. 6 and no. 7 in table 1. These two samples were nitrided at the same time under the same processing parameters, and the in-situ ion bombardment cleaning procedure just before the nitriding was skipped. After nitriding, sample no. 6 was allowed to cool with the substrate holder, while sample no.7 was quenched in oil. Fig. 10 and 11 shows the cross-sectional morphology of these two samples. No dual layer structure is observed in either of the two

samples. This can be confirmed by the corresponding XRD patterns shown in fig. 12; no additional peaks are observed between peaks of the γ_{N_1} phase and that of the substrate. Therefore the ion bombardment cleaning is necessary to produce the γ_{N_2} sublayer.

The primary aim of an in-situ ion bombardment cleaning just before nitriding is to remove the native oxide layer from the sample surface. But it also an important role in the formation of the γ_{N_2} phase as being discussed above. Therefore a sample was then merely ion bombarded in a 50%Ar+50%H₂ plasma without a following nitriding treatment (sample no. 8 in table1), so as to investigate the effect of this procedure on the formation of the γ_{N_2} phase. A homogeneous layer, which is distinct from the substrate, can be observed on surface of the sample (fig. 13). The corresponding XRD pattern (fig. 14) confirms that a new phase, probably the γ_{N_2} phase, forms owing to the ion bombardment. Fig. 15 shows the concentration depth profiles of this sample obtained by SNMS analysis. It is interesting to note that a nitrogen concentration up to near 10 at.% is found on the top surface, and the nitrogen content gradually decrease to zero at a depth of around 2.0 μ m. Since no

nitrogen gas was introduced into the reactor during the ion bombardment, it should be the residual nitrogen in the reactor that contributes to the additional nitrogen in

the layer. A carbon rich region, also observed in sample no. 1, is observed between of 1.0 μm and 5.5 μm .

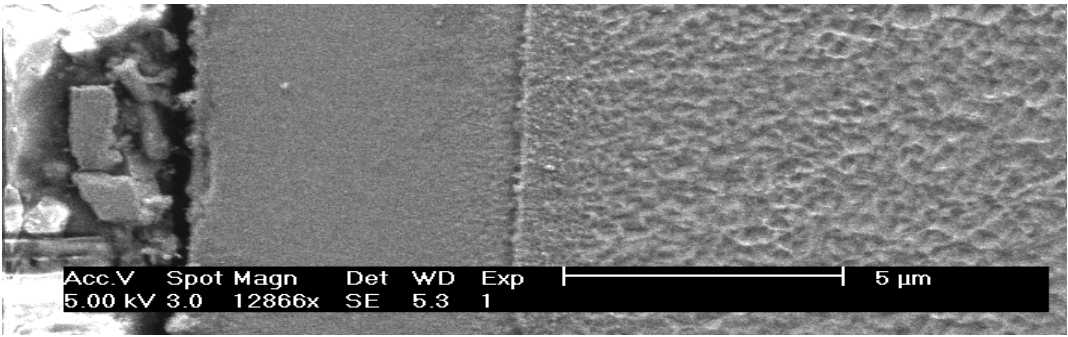


Fig. 10. SEM micrograph of the nitrided layer for sample no.6 in table 1

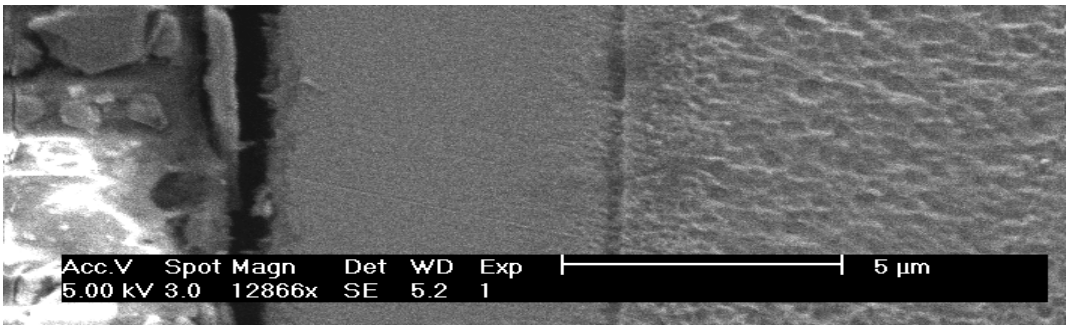


Fig. 11. SEM micrograph of the nitrided layer for sample no.7 in table 1

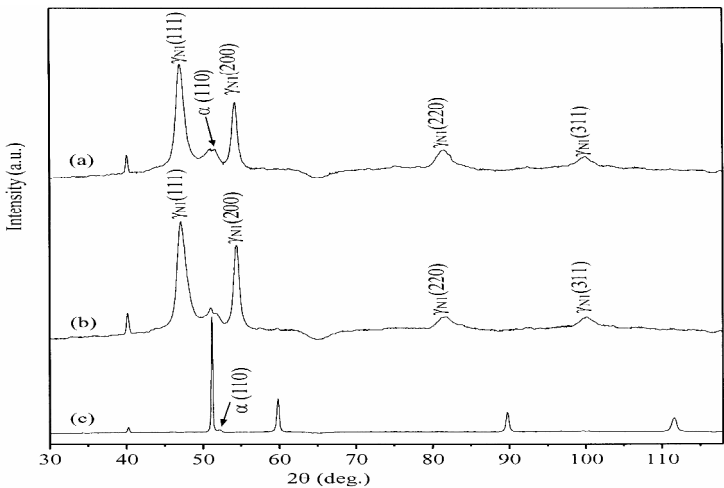


Fig. 12. XRD patterns for sample no.6 (a), no. 7 (b) described in table 1, and for the original AISI 316L substrate (c), with CoK α radiation at incident angle of 10°

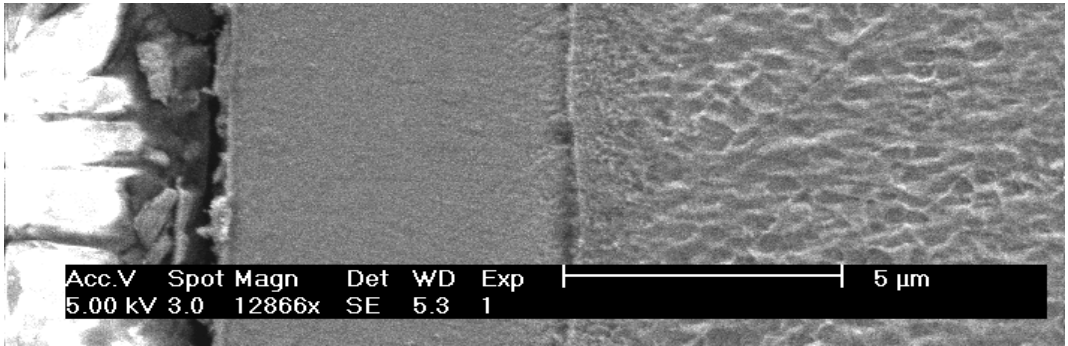


Fig. 13. SEM micrograph of the nitrided layer for sample no.8 described in table 1

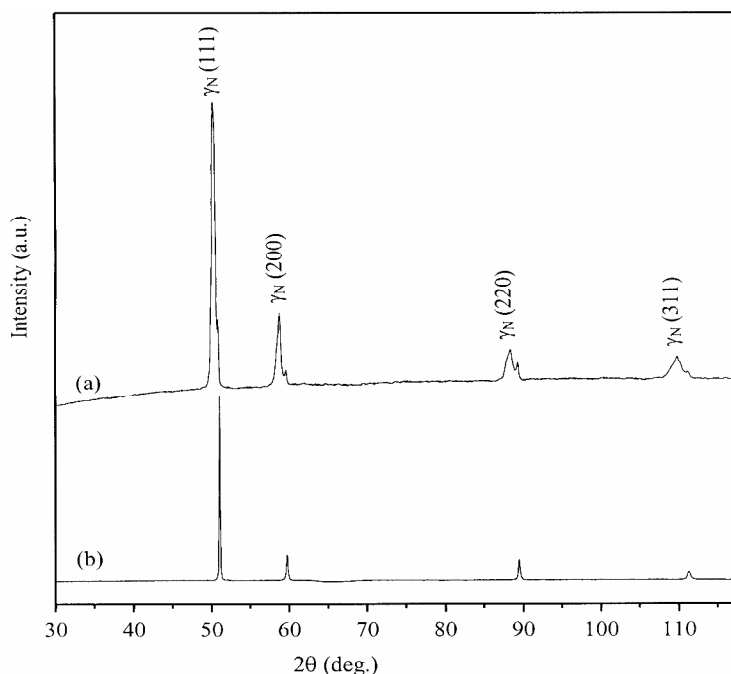


Fig. 14. XRD patterns for sample no.8 (a) described in table 1, and for the original AISI 316L substrate (b), with $\text{CoK}\alpha$ radiation at incident angle 25° .

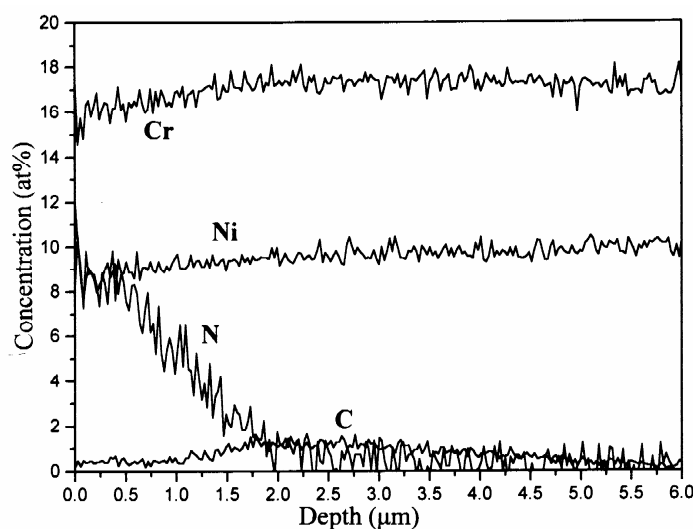


Fig. 15. SNMS concentration depth profiles of sample no. 8 in table 1

The lattice parameters of the two γ_N phases produced under different conditions are listed in table 2. The lattice parameter of the substrate is 0.359 nm. From this table we can see that the lattice parameter of the γ_{N1} phase lies between 0.384 and 0.390 nm, while the lattice parameter of the γ_{N2} phase lies between 0.360 and 0.370 nm, depending on the processing parameters and the nature of substrate. The lattice expansion of γ_{N1} phase is 7-8% while that of the γ_{N2} phase is less than 2%. Evidently, this can be contributed to the different solid solution nitrogen content in the γ_{N1} phase and the γ_{N2} phase. A new model for the formation of the γ_{N2} layer is then suggested as shown in fig. 16, based on the results presented above. Except for a new cathode, there is always a intruded layer on the substrate holder,

in which nitrogen exists in forms of solid solution or metal nitrides due to previous nitriding treatments. During the ion bombardment cleaning procedure, residual nitrogen in the substrate holder is sputtered by the Ar ions or the fast Ar atoms which collide with the substrate holder surface. The sputtered nitrogen atoms entering the plasma are then ionized in the region near the surface of the substrate holder. Since the nitrogen potential of the sample surface is much lower than that of the plasma, and the sample surface is rather fresh owing to the ion bombardment, it is easy for the sample surface to capture the incoming nitrogen ions or atoms. And then a region rich in nitrogen forms as a result of the diffusion of the captured nitrogen atoms into the sample. Similarly, organic compounds from

the different surfaces of the reactor escape from the sample walls due to the interaction with argon bombardment and / or hydrogen. Such a carbon contamination only occurs during the ion bombardment cleaning procedure, that why the carbon layer is limited to a position near the interface with the nitrided layer and the substrate. Accumulation of carbon at the front of the nitrogen diffusion layer during the nitriding of FeCrC alloys was reported by van Wiggeren et al.[18]. At the end of the ion bombardment cleaning, a layer

composed of two overlapped regions, one being nitrogen enriched and the other carbon enriched, forms at the surface. This layer corresponds to the γ_{N_2} layer that is in fact a γ_{CN} layer. During the nitriding treatment, nitrogen atoms “rush” into the sample surface owing to the high nitrogen potential in the plasma, and diffuse toward the sample’s core. Then the γ_{N_2} phase at the diffusing front is transformed into the γ_{N_1} phase after solution of more nitrogen. Meanwhile, the γ_{N_2} layer is transferred to a deeper position.

Tab. 2. Lattice parameters calculated from the (111) diffraction line, and the layer thicknesses of the nitrided samples listed in table 1.

Sample's ID	γ_{N_1}	γ_{N_2}	Mean layer thickness (μm)
No. 1	3.890	3.661	4.2
No. 2	3.881	3.626	4.7
No. 3	3.871	3.649	6.3
No. 4	3.864	3.643	6.0
No. 5	3.840	3.637	5.2
No. 6	3.868		7.0
No. 7	3.880		8.0
No. 8		3.625	5.8

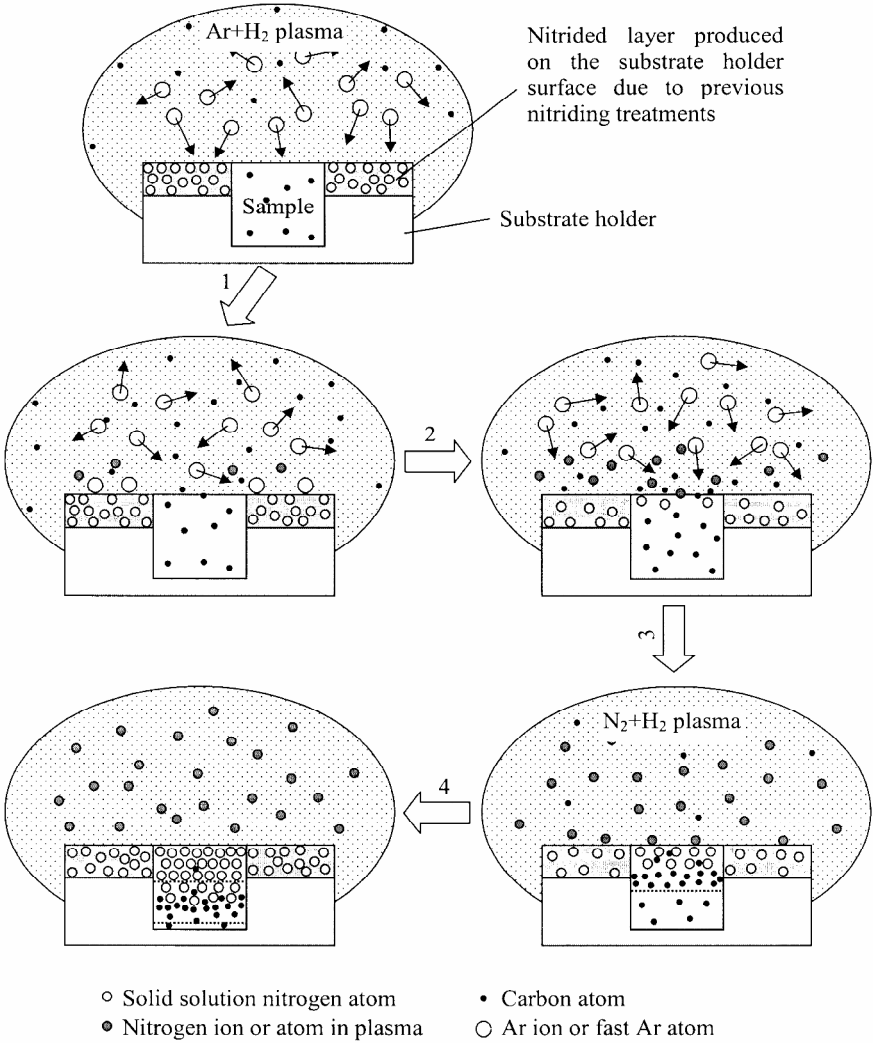


Fig. 16. Schematic for describing the formation of the γ_{N_2} layer

5. Conclusions

Plasma assisted nitriding of austenitic stainless steel AISI 316L at 420°C produces two distinct γ_N layers with well-defined interface: γ_{N1} top layer with relative high solid solution nitrogen content ranged from 10 at.% to nearly 30 at.%, and γ_{N2} sublayer with relative low solid solution nitrogen content less than 10 at.% and a small amount of carbon. It was found that an in-situ ion bombardment cleaning in Ar+H₂ plasma before the nitriding treatment is the necessary condition to produce the γ_{N2} layer. The formation of the γ_{N2} layers is not connected to the cooling state of the sample after a nitriding treatment.

A model for the formation of the γ_{N2} sublayer is then suggested as follow: during the ion bombardment cleaning procedure, the residual nitrogen in the reactor is sputtered into the plasma owing to the bombardment of Ar species. Some of the sputtered nitrogen species are absorbed by the sample surface and then diffuses into the sample. At the same time organic compounds are also sputtered from the walls of the reactor and a redistribution of carbon and nitrogen in the sample occurs just beneath the sample surface. Thus a layer constituted by two overlapped regions with low contents of nitrogen and carbon forms during the ion bombardment cleaning, which becomes the precursor of the γ_{N2} sublayer during the subsequent nitriding.

References

- [1] Sundararaman, D., Kuppusami, P., Raghunathan, V.S., *Some Observations on the Ion Nitriding Behavior of a Type 316 Stainless Steel*, Surfaces. Technology, 1983, 18(4), pp. 341-347.
- [2] Zhang, Z.L., Bell, T., *Structured and corrosion resistance of plasma nitrided stainless steel*, Surf. Eng. 1985, 1920, pp. 131-136.
- [3] Rolinski, E., *Effect of Plasma Nitriding Temperature on Surface Properties of Austenitic Stainless Steel*, Surf. Eng., 1987,3(1), pp. 35-40.
- [4] Sundararaman, D., Kuppusami, P., Raghunathan, V.S., *A Study of Plasma-Nitrided AISI Type 316 Stainless Steel*, Surf. and Coat. Technol., 1987, 30 (4), pp. 343-354.
- [5] Angelini, E., Burdese, A., de Benedetti, B., *Ion-Nitriding of Austenitic Stainless Steel*, Metall. Sci. Technol., 1988, 6(2), pp. 33-39.
- [6] Saker, A., Leroy, C., Michel, H., Franz, H., *Properties of Sputtered Stainless Steel-Nitrogen Coatings and Structural Analogy with Low Temperature plasma Nitrided Layer Austenitic Steels*, Mater. Sci. Eng. A, 1991, 140 (1/2), pp. 702-708.
- [7] Meletis, E.I., Yan, S., *Low-Pressure ion Nitriding of AISI 304 Austenitic Stainless Steel with an Intensified Glow Discharge*, J. Vac. Sci. Technol. A, 1993,11 (1), pp. 25-33.
- [8] Lei, M.K., Zhang, M.K., *Microstructure and Corrosion Resistance of Plasma Source ion Nitrided Austenitic Stainless Steel*, J. Vac. Sci. Technol. A, 1997, 15 (2), pp. 421-427.
- [9] Sun, Y., Bell, T., *Sliding Wear Characteristics of Low Temperature Plasma Nitrided 316 Austenitic Stainless Steel*, Wear 1998, 218 (1), pp. 34-42.
- [10] Williamson, D.L., Davi, J.A., Wilbur, P.J. *Effect of austenitic stainless steel composition on low-energy, high-flux, nitrogen ion beam processing*, Surf. And coat. Technol., 1998, 103/104, pp. 178-184.
- [11] Blawert, C., Mordike, B.L., Jiraskova, Y., Schneeweiss, O., *Structure and Composition of Expanded Austenitic Produced by Nitrogen Plasma Immersion Ion Implantation of Stainless Steels X6CrNiTi1810 and X2CrNiMoN2253*, Surf. And Coat. Technol. 1999, 116/119, pp. 189-198.
- [12] Ozturk, O., Williamson, D.L., *Phase and Composition Depth Distribution Analyses of Low Energy, high flux N implant stainless steel*, J. Appl. Phys., 1995, 77 (8), pp. 3839-3850.
- [13] Czerwiec, T., Michel, H., Bergmann, E., *Low-Pressure, high-density plasma nitriding: mechanisms, technology and results*, Surf. and Coat. Technol., 1998, 108/109, pp. 182-190.
- [14] Sun, Y., Li, X.Y., Bell, T., *X-ray Diffraction Characterization of Low Temperature Plasma Modification Nitrided Austenitic Stainless Steel*, J. Mater. Sci., 1999, 34 (19), pp. 4793-4802.
- [15] Marchev, K., Landis, M., Vallerio, R., Cooper, C.V., Giessen, B.C., *The m Phase Layer on ion Nitrided Austenitic Stainless Steel (III): an Epitaxial relationship Between the m Phase and the γ Parent Phase and a Review of Structural Identifications of this Phase*, Surf. and Coat. Technol. 1999, 116/119, pp. 184-188.
- [16] Czerwiec, T., Renevier, N., Michel, H., *Low Temperature Plasma-Assisted Nitriding*, Surf. and Coat. Technol. 2000, 131, pp. 267-277.
- [17] Renevie, N., Collignon, P., Michel, H., Czerwiec, T., *Low Temperature Nitriding of AISI 316L Stainless steel and Titanium in a Low Pressure Arc Discharge*, Surf. and Coat. Technol. 1999, 111, pp. 128-133.
- [18] Van Wigger, P.C., Rozendaal, H.C.F., Mitterneijer, E.J., *The Nitriding Behaviour of Iron-Chromium-carbon Alloys*, J. Matter. Sci., 1985, 20, pp. 4561-4582.